

SN74LV374A 具有三态输出的八路边沿触发 D 类触发器

1 特性

- V_{CC} 工作范围为 2V 至 5.5V
- 5V 时 t_{pd} 最大值为 9.5ns
- V_{OLP} (输出接地反弹) 典型值小于 0.8V ($V_{CC} = 3.3V$, $T_A = 25^\circ C$)
- V_{OHV} (输出 V_{OH} 下冲) 典型值大于 2.3V ($V_{CC} = 3.3V$, $T_A = 25^\circ C$ 时)
- 所有端口上均支持以混合模式电压运行
- I_{off} 支持局部关断模式运行
- 闩锁性能超过 250mA, 符合 JESD 17 规范

2 应用

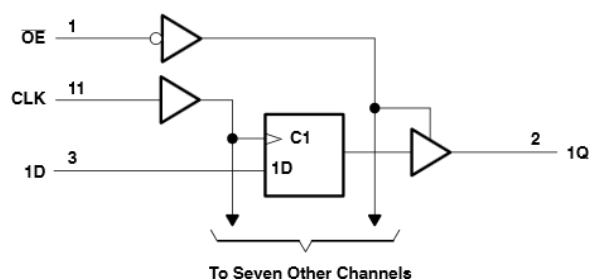
- 可编程逻辑控制器 (PLC)
- DCS 和 PAC: 模拟输入模块
- 火车、有轨电车和地铁车厢
- 交流逆变器驱动器
- 打印机

3 说明

SN74LV374A 器件是八路边沿触发 D 类触发器, 旨在 2V 至 5.5V V_{CC} 下运行。

封装信息

器件型号	封装	封装尺寸 (标称值)
SN74LV374A	DB (SSOP, 20)	7.20mm × 5.30mm
	DW (SOIC, 20)	12.80mm × 7.50mm
	NS (SO, 20)	12.60mm × 5.30mm
	PW (TSSOP, 20)	6.50mm × 4.40mm



所示引脚编号用于 DB、DW、NS、PW 和 RGY 封装。

逻辑图 (正逻辑)

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision K (December 2022) to Revision L (March 2023)	Page
• 更新了文档的结构布局和表格的格式.....	1
• Updated thermal values for DW package from $R^{\theta}_{JA} = 79.2$ to 102.3 , $R^{\theta}_{JC}(\text{top}) = 43.7$ to 69.9 , $R^{\theta}_{JB} = 47$ to 70.8 , $\Psi_{JT} = 18.6$ to 46.4 , $\Psi_{JB} = 46.5$ to 70.4 , all values in $^\circ\text{C}/\text{W}$	5
Changes from Revision J (March 2015) to Revision K (December 2022)	Page
• 通篇更新了表格、图和交叉参考的格式.....	1
Changes from Revision I (March 2015) to Revision J (October 2016)	Page
• Added Junction temperature, T_J	4
• Deleted " $V_{CC} \times 0.3$ " from MIN and added " $V_{CC} \times 0.3$ " to MAX for SN54LV374A and SN74LV374A.....	5
• Changed "SN54LV384A" to "SN54LV374A" in <i>Electrical Characteristics</i> table.....	6
• Added <i>Related Links</i> section, <i>Receiving Notification of Documentation Updates</i> section, and <i>Community Resources</i> section.....	15
Changes from Revision H (April 2005) to Revision I (March 2015)	Page
• 添加了引脚配置和功能部分、ESD 等级表、特性说明部分、器件功能模式、应用和实现部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分.....	1

5 Pin Configuration and Functions

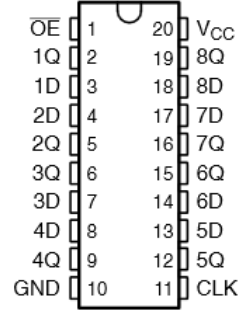


图 5-1. DB, DW, NS, or PW Package 20-PIN SSOP, SOIC, SO, or TSSOP (Top View)

表 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
OE	1	I	Enable pin
1Q	2	O	Output 1
1D	3	I	Input 1
2D	4	I	Input 2
2Q	5	O	Output 2
3Q	6	O	Output 3
3D	7	I	Input 3
4D	8	I	Input 4
4Q	9	O	Output 4
GND	10	-	Ground pin
CLK	11	I	Clock pin
5Q	12	O	Output 5
5D	13	I	Input 5
6D	14	I	Input 6
6Q	15	O	Output 6
7Q	16	O	Output 7
7D	17	I	Input 7
8D	18	I	Input 8
8Q	19	O	Output 8
V _{CC}	20	-	Power pin

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	-0.5	7	V
V _I	Input voltage ⁽²⁾	-0.5	7	V
V _O	Voltage applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	7	V
V _O	Output voltage ^{(2) (3)}	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current (V _I < 0)		-20	mA
I _{OK}	Output clamp current (V _O < 0)		-50	mA
I _O	Continuous output current (V _O = 0 to V _{CC})		±35	mA
	Continuous current through V _{CC} or GND		±70	mA
T _J	Junction temperature		150	°C
T _{stg}	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) This value is limited to 5.5 V maximum.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000
		Machine Model (A115-A)	±200

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		SN74LV374A		UNIT	
		MIN	MAX		
V _{CC}	Supply voltage	2	5.5	V	
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5	V	
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.77		
V _{IL}	Low-level input voltage	V _{CC} = 2 V	0.5	V	
		V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.3		
		V _{CC} = 3 V to 3.6 V	V _{CC} × 0.3		
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.3		
V _I	Input voltage	0	5.5	V	
V _O	Output voltage	High or low state	0	V _{CC}	V
		3-state	0	5.5	
I _{OH}	High-level output current	V _{CC} = 2 V	-50	μA	
		V _{CC} = 2.3 V to 2.7 V	-2		
		V _{CC} = 3 V to 3.6 V	-8	mA	
		V _{CC} = 4.5 V to 5.5 V	-16		
I _{OL}	Low-level output current	V _{CC} = 2 V	50	μA	
		V _{CC} = 2.3 V to 2.7 V	2		
		V _{CC} = 3 V to 3.6 V	8	mA	
		V _{CC} = 4.5 V to 5.5 V	16		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 2.3 V to 2.7 V	200	ns/V	
		V _{CC} = 3 V to 3.6 V	100		
		V _{CC} = 4.5 V to 5.5 V	20		
T _A	Operating free-air temperature	-40	125	°C	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See [Implications of Slow or Floating CMOS Inputs](#), SCBA004.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74LV374A				UNIT
		DB (SSOP)	DW (SOIC)	NS (SO)	PW (TSSOP)	
		20 PINS	20 PINS	20 PINS	20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	94.5	102.3	76.7	102.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	56.4	69.9	43.2	36.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	49.7	70.8	44.2	53.6	°C/W
ψ _{JT}	Junction-to-top characterization parameter	18.5	46.4	16.8	2.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	49.3	70.4	43.8	52.9	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	SN74LV374A - 40°C to +85°C			SN74LV374A - 40°C to +125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V _{OH}	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.1			V _{CC} -0.1			V
	I _{OH} = -2 mA	2.3 V	2			2			
	I _{OH} = -8 mA	3 V	2.48			2.48			
	I _{OH} = -16 mA	4.5 V	3.8			3.8			
V _{OL}	I _{OL} = 50 μA	2 V to 5.5 V				0.1			V
	I _{OL} = 2 mA	2.3 V				0.4			
	I _{OL} = 8 mA	3 V				0.44			
	I _{OL} = 16 mA	4.5 V				0.55			
I _I	V _I = 5.5 V or GND	0 to 5.5 V				±1			μA
I _{OZ}	V _O = V _{CC} or GND	5.5 V				±5			μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V				20			μA
I _{off}	V _I or V _O = 0 to 5.5 V	0				5			μA
C _i	V _I = V _{CC} or GND	3.3 V	2.9			2.9			pF

6.6 Switching Characteristics, V_{CC} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range, V_{CC} = 2.5 V ± 0.2 V (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN74LV374A - 40°C to +85°C		SN74LV374A - 40°C to +125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f _{max}			C _L = 15 pF	60 ⁽¹⁾	105 ⁽¹⁾		50		50		MHz
			C _L = 50 pF	50	85		40		40		
t _{pd}	CLK	Q	C _L = 15 pF		9.7 ⁽¹⁾	16.3 ⁽¹⁾	1	19	1	20.5	ns
t _{en}	\overline{OE}	Q			8.9 ⁽¹⁾	15.9 ⁽¹⁾	1	19	1	20.5	
t _{dis}	\overline{OE}	Q			6.3 ⁽¹⁾	12.6 ⁽¹⁾	1	15	1	16.5	
t _{pd}	CLK	Q	C _L = 50 pF		11.8	19.3	1	23	1	24.5	ns
t _{en}	\overline{OE}	Q			10.9	18.8	1	22	1	23.5	
t _{dis}	\overline{OE}	Q			8.2	17.3	1	19	1	20.5	
t _{sk(o)}								2		2	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.7 Switching Characteristics, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN74LV374A - 40°C to +85°C		SN74LV374A - 40°C to +125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f_{max}			$C_L = 15\text{ pF}$	80 ⁽¹⁾	150 ⁽¹⁾		70		70	MHz	
			$C_L = 50\text{ pF}$	55	110		50		50		
t_{pd}	CLK	Q	$C_L = 15\text{ pF}$		6.8 ⁽¹⁾	12.7 ⁽¹⁾	1	15	1	16	ns
t_{en}	\overline{OE}	Q			6.3 ⁽¹⁾	11 ⁽¹⁾	1	13	1	14	
t_{dis}	\overline{OE}	Q			4.7 ⁽¹⁾	10.5 ⁽¹⁾	1	12.5	1	13.5	
t_{pd}	CLK	Q	$C_L = 50\text{ pF}$		8.3	16.2	1	18.5	1	19.5	ns
t_{en}	\overline{OE}	Q			7.7	14.5	1	16.5	1	17.5	
t_{dis}	\overline{OE}	Q			5.9	14	1	16	1	17	
$t_{sk(o)}$								1.5		1.5	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.8 Switching Characteristics, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$

over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN74LV374A - 40°C to +85°C		SN74LV374A - 40°C to +125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f_{max}			$C_L = 15\text{ pF}$	130 ⁽¹⁾	205 ⁽¹⁾		110		110	MHz	
			$C_L = 50\text{ pF}$	85	1705		75		75		
t_{pd}	CLK	Q	$C_L = 15\text{ pF}$		4.9 ⁽¹⁾	8.1 ⁽¹⁾	1	9.5	1	10.5	ns
t_{en}	\overline{OE}	Q			4.6 ⁽¹⁾	7.6 ⁽¹⁾	1	9	1	10	
t_{dis}	\overline{OE}	Q			3.4 ⁽¹⁾	6.8 ⁽¹⁾	1	8	1	9	
t_{pd}	CLK	Q	$C_L = 50\text{ pF}$		5.9	10.1	1	11.5	1	12.5	ns
t_{en}	\overline{OE}	Q			5.5	9.6	1	11	1	12	
t_{dis}	\overline{OE}	Q			4	8.8	1	10	1	11	
$t_{sk(o)}$								1		1	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.9 Timing Requirements

over recommended operating free-air temperature range, (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

		$T_A = 25^\circ\text{C}$		SN74LV374A - 40°C to +85°C		SN74LV374A - 40°C to +125°C		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$								
t_w	Pulse duration, CLK high or low	6		7		7		ns
t_{su}	Setup time, data before CLK \uparrow	5		5.5		6		ns
t_h	Hold time, data after CLK \uparrow	2.5		2.5		3		ns
$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$								
t_w	Pulse duration, CLK high or low	5		5.5		5.5		ns
t_{su}	Setup time, data before CLK \uparrow	4.5		4.5		5		ns
t_h	Hold time, data after CLK \uparrow	2		2		2.5		ns
$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$								
t_w	Pulse duration, CLK high or low	5		5		5		ns
t_{su}	Setup time, data before CLK \uparrow	3		3		3.5		ns
t_h	Hold time, data after CLK \uparrow	2		2		2.5		ns

6.10 Noise Characteristics

$V_{CC} = 3.3\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ ⁽¹⁾

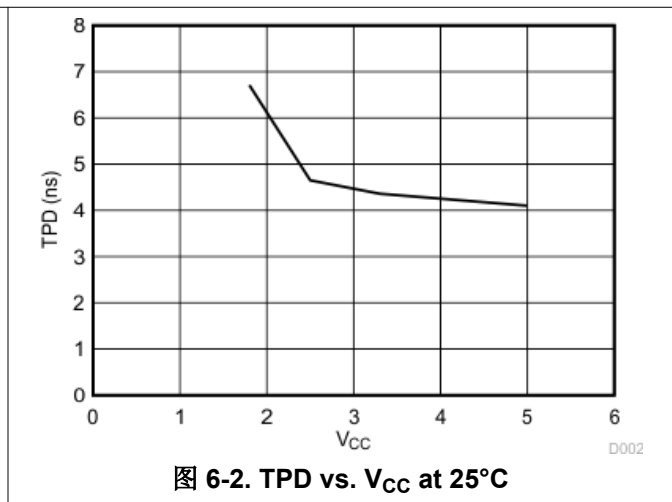
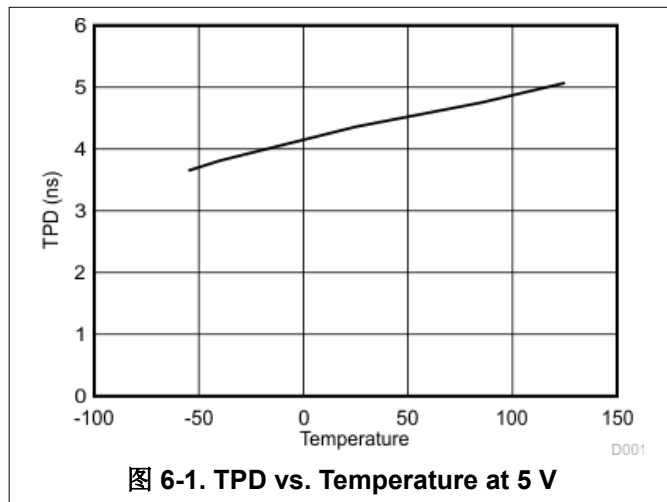
PARAMETER		SN74LV374A			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.6	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		-0.5	-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	2.9	2.9		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

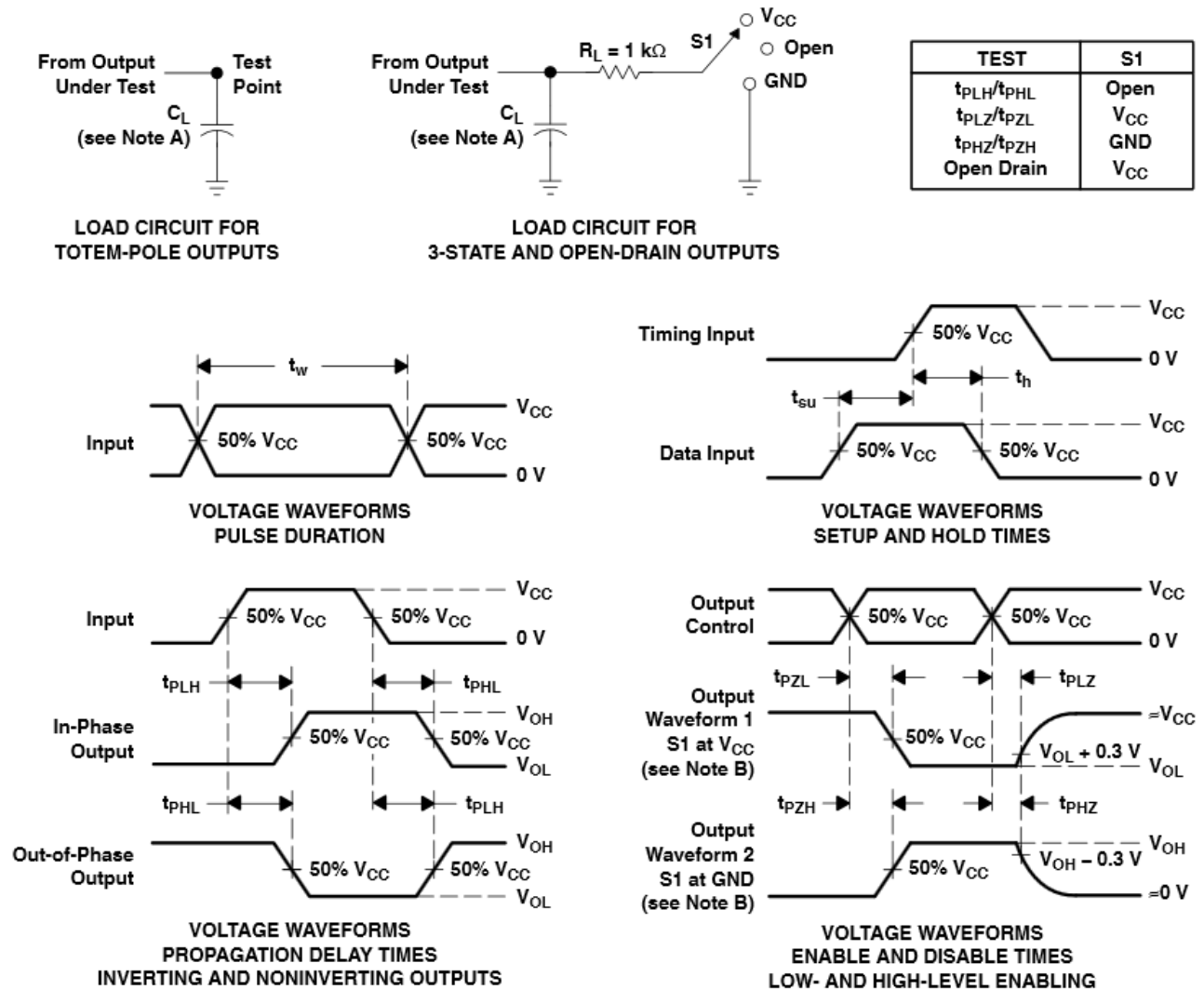
6.11 Operating Characteristics, $T_A = 25^\circ\text{C}$

PARAMETER			TEST CONDITIONS		V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance	Outputs enabled	$C_L = 50\text{ pF}$,	$f = 10\text{ MHz}$	3.3 V	21.1	pF
					5 V	22.8	

6.12 Typical Characteristics



7 Parameter Measurement Information



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR $\leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
 - D. The outputs are measured one at a time, with one input transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PHL} and t_{PLH} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

图 7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

The SN74LV374A devices are octal edge-triggered D-type flip-flops designed for 2 V to 5.5 V V_{CC} operation. These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bi-directional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs. A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components. \overline{OE} does not affect internal operations of the latch.

Old data can be retained or new data can be entered while the outputs are in the high-impedance state. To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The output of the device is unknown until the first valid rising clock edge occurs while V_{CC} is within the [# 6.3](#) range.

8.2 Functional Block Diagram

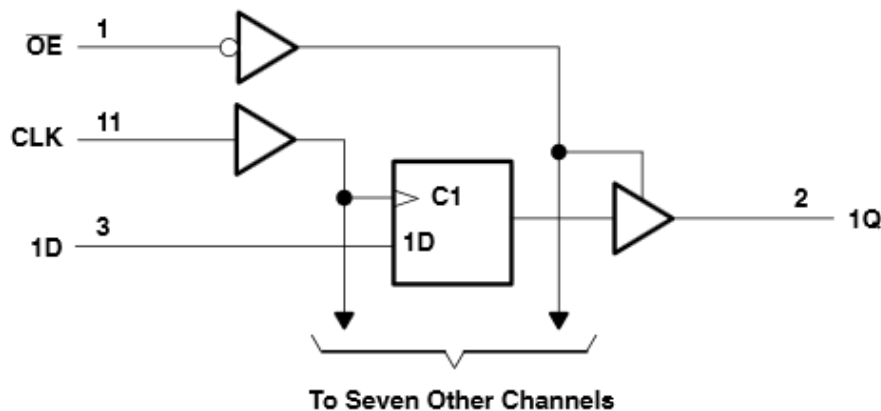


图 8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

The device's wide operating range allows it to be used in a variety of systems that use different logic levels. The low propagation delay allows fast switching and higher speeds of operation. In addition, the low ground bounce stabilizes the performance of non-switching outputs while another output is switching.

8.4 Device Functional Modes

表 8-1 lists the functional modes of the SN74LV374A devices.

表 8-1. Function Table (Each Flip-Flop)

INPUTS			OUTPUT Q
OE	CLK	D	
L	↑	H	H
L	↑	L	L
L	L	X	Q_0

表 8-1. Function Table (Each Flip-Flop) (continued)

INPUTS			OUTPUT Q
OE	CLK	D	
H	X	X	Z

9 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

9.1 Application Information

The SN74LV374A is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs accept voltages up to 5.5 V allowing down translation to the V_{CC} level.

9.2 Typical Application

图 9-1 shows how the slower edges can reduce ringing on the output compared to higher drive parts like AC.

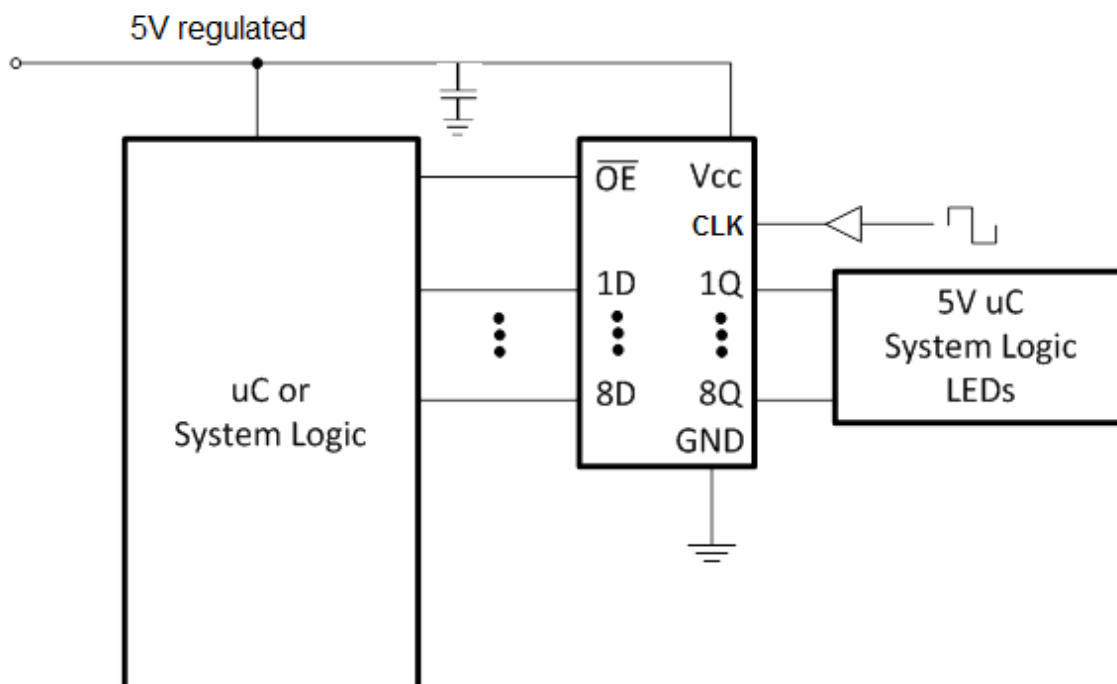


图 9-1. Typical Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so consider routing and load conditions to prevent ringing.

9.2.2 Detailed Design Procedure

- Recommended Input conditions:
 - Rise time and fall time specs see ($\Delta t / \Delta V$) in [# 6.3](#).
 - Specified High and low levels. See (V_{IH} and V_{IL}) in [# 6.3](#).
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
- Recommended output conditions:
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC} .

9.2.3 Application Curve

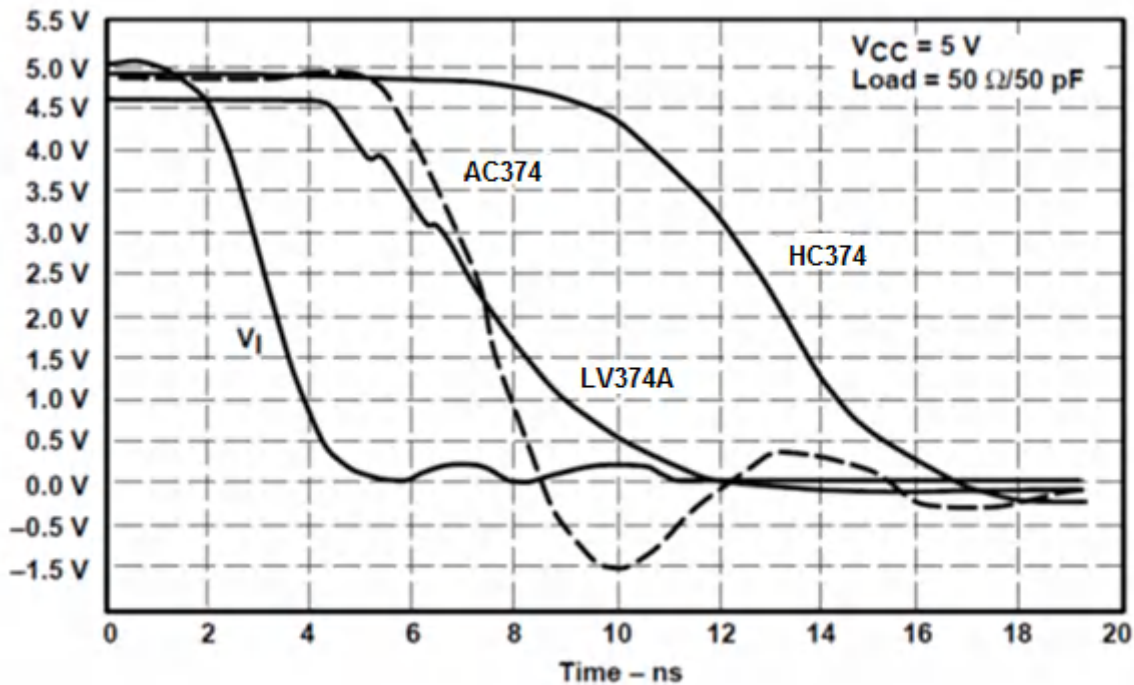


图 9-2. Switching Characteristics Comparison

9.3 Power Supply Recommendations

9.4 Layout

9.4.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only three of the four buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient. Floating outputs is generally acceptable, unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O' s so they also cannot float when disabled.

9.4.1.1 Layout Example

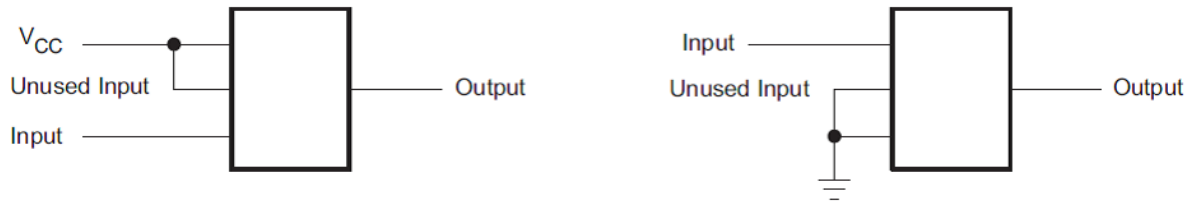


图 9-3. Layout Example

10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation see the following:

[Implications of Slow or Floating CMOS Inputs](#), SCBA004

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

10.4 Trademarks

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10.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

10.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV374ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples
SN74LV374ADW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 125	LV374A	
SN74LV374ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples
SN74LV374ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV374A	Samples
SN74LV374APW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 125	LV374A	
SN74LV374APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV374A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LV374A :

- Automotive : [SN74LV374A-Q1](#)
- Enhanced Product : [SN74LV374A-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV374ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV374ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LV374ADWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74LV374ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LV374APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV374ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LV374ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV374ADWR	SOIC	DW	20	2000	356.0	356.0	41.0
SN74LV374ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV374APWR	TSSOP	PW	20	2000	356.0	356.0	35.0

DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



4214851/B 08/2019

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4214851/B 08/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/B 08/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220724/A 05/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220206/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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